

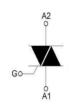
Features

- Blocking voltage to 800 V
- RMS on-state current to 1 A
- General purpose bidirectional switching



Package Marking and Ordering Information

Product ID	Pack	Packing Method	Qty(PCS)	
BT131-800D	SOT-223-2L	Tape and Reel	3000	



Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Value	Unit	
V _{DRM} /V _{RRM}	repetitive peak off-state voltage		800	V	
I _{T(RMS)}	RMS on-state current		1	Α	
	Non repetitive surge peak	t = 20ms T _j = 25°C	10	_	
I _{TSM}	on-state current	t = 16.7ms T _j = 25°C	8	Α	
l ² t	I ² t for fusing	t = 10 ms	1	A ² s	
dl/dt	Critical-rate of rise of I II III commutation current IV	I _G =2I _{GT} tr≤100ns F=120Hz	50 10	A/us	
I _{GM}	Peak Gate Current	T _j =125°C tp=20µs	0.3	Α	
V _{GM}	Peak gate voltage	T _j =125 °C	1	V	
P _{GM}	Peak gate power	T _j =125 °C	0.8	W	
P _{G(AV)}	Average Gate Power Dissipation	T _j =125 °C	0.4	W	
Tj	Junction Temperature	-	-40 ~ 125	°C	
T stg	Storage Temperature	-	-40 ~ 150	°C	

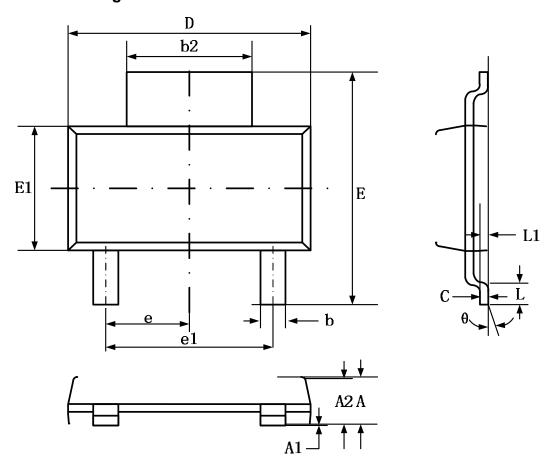


Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter		Symbol	Test conditions		Min	Тур	Max	Unit
Repetitive Peak Off-State Current		I _{DRM,} I _{RRM}	V _{DRM} =V _{RRM} T _j =25°C				5	μΑ
Repetitive Peak Reverse Current		-Draw, radw	$V_{DRM} = V_{RRM} T_j = 125 °C$				1	mA
Gate non-trigger voltage		V_{GD}	$V_D = 1/2V_{DRM}$		0.2			V
On-state voltage		V_{TM}	I _T =0.8A,t _p =380us				1.65	V
	I	- I _{GT}	T ₂ (+), G(+)	V _D =12V			3	mA
Gate trigger current	II		T ₂ (+), G(-)				6	
Gate trigger current	III		T ₂ (-), G(-)	R _L =100Ω	_=100Ω		4	
	IV		T ₂ (-), G(+)				8	
	I	V _{GT}	T ₂ (+), G(+)			0.8	2	V
Gate trigger voltage	II		T ₂ (+), G(-)	V _D =12V		8.0	2	
Gate trigger voltage	III		T ₂ (-), G(-)	R _L =100Ω		0.8	2	
	IV		T ₂ (-), G(+)			8.0	2.5	
Holding current		l _Η	V _D =12V ,I _{GT} =100mA				30	mA
Critical-rate of rise of commutation		dV/dt	V _{DM} =67%V _{DRM}				50	V/us
voltage			Gate open T _j =125 °C					
Rate of change of commutating voltage		(dl/dt)c	V _{DM} =400V T _j =125 °C				20	V/us
			(dl/dt)c=5.4A/ms Gate open					
Turn-on time		t _{gt}	I _{TM} =16A ,V _{DM} =V _{DRM(MAX)} I _G =0.1A,dI _G dt=5A uS				2	us



SOT-223-2L Package Outline Dimensions



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А		1.80		0.071	
A1	0.02	0.10	0.001	0.004	
A2	1.50	1.70	0.059	0.067	
b	0.66	0.84	0.026	0.033	
b2	2.90	3.10	0.114	0.122	
С	0.23	0.35	0.009	0.014	
D	6.30	6.70	0.248	0.264	
E	6.70	7.30	0.264	0.287	
E1	3.30	3.70	0.130	0.146	
е	2.30 BSC.		0.091 BSC.		
e1	4.60 BSC.		0.182 BSC.		
L	0.81		0.032		
L1	0.25 BSC.		0.032 BSC.		
θ	0°	10°	0°	10°	



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